# NSN 5962-01-260-6506

Memory Microcircuit - Page 1 of 1



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## **Body Length:**

Between 1.235 inches and 1.285 inches

## Body Width:

Between 0.515 inches and 0.600 inches

## **Body Height:**

Between 0.145 inches and 0.187 inches

# Maximum Power Dissipation Rating:

525.0 milliwatts

#### **Operating Tempurature Range:**

-0.0/+70.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+125.0 degrees celsius

#### **Features Provided:**

Programmable and ultraviolet erasable and low power and high performance

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Metal oxide-semiconductor logic

#### Input Circuit Pattern:

13 input

## **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

26.5 volts power source

#### **Time Rating Per Chacteristic:**

450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

## Fiig:

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